

# UNR911xJ Series (UN911xJ Series)

## Silicon PNP epitaxial planar type

For digital circuits

### ■ Features

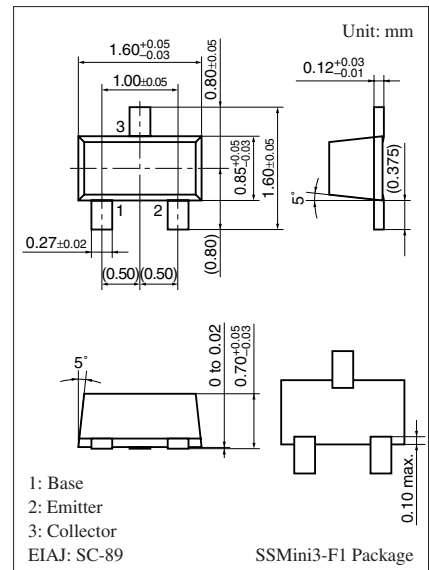
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- SS-Mini type package, allowing automatic insertion through tape packing.

### ■ Resistance by Part Number

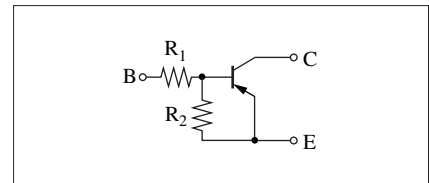
	Marking Symbol	(R <sub>1</sub> )	(R <sub>2</sub> )
• UNR9110J (UN9110J)	6L	47 kΩ	—
• UNR9111J (UN9111J)	6A	10 kΩ	10 kΩ
• UNR9112J (UN9112J)	6B	22 kΩ	22 kΩ
• UNR9113J (UN9113J)	6C	47 kΩ	47 kΩ
• UNR9114J (UN9114J)	6D	10 kΩ	47 kΩ
• UNR9115J (UN9115J)	6E	10 kΩ	—
• UNR9116J (UN9116J)	6F	4.7 kΩ	—
• UNR9117J (UN9117J)	6H	22 kΩ	—
• UNR9118J (UN9118J)	6I	0.51 kΩ	5.1 kΩ
• UNR9119J (UN9119J)	6K	1 kΩ	10 kΩ
• UNR911AJ	6X	100 kΩ	100 kΩ
• UNR911BJ	6Y	100 kΩ	—
• UNR911CJ	6Z	—	47 kΩ
• UNR911DJ (UN911DJ)	6M	47 kΩ	10 kΩ
• UNR911EJ (UN911EJ)	6N	47 kΩ	22 kΩ
• UNR911FJ (UN911FJ)	6O	4.7 kΩ	10 kΩ
• UNR911HJ (UN911HJ)	6P	2.2 kΩ	10 kΩ
• UNR911LJ (UN911LJ)	6Q	4.7 kΩ	4.7 kΩ
• UNR911MJ	EI	2.2 kΩ	47 kΩ
• UNR911NJ	EW	4.7 kΩ	47 kΩ
• UNR911TJ (UN911TJ)	EY	22 kΩ	47 kΩ
• UNR911VJ	FC	2.2 kΩ	2.2 kΩ

### ■ Absolute Maximum Ratings T<sub>a</sub> = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-50	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-50	V
Collector current	I <sub>C</sub>	-100	mA
Total power dissipation	P <sub>T</sub>	125	mW
Junction temperature	T <sub>j</sub>	125	°C
Storage temperature	T <sub>stg</sub>	-55 to +125	°C



### Internal Connection



(Note) The part numbers in the parenthesis show conventional part number.

**■ Electrical Characteristics**  $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$ 

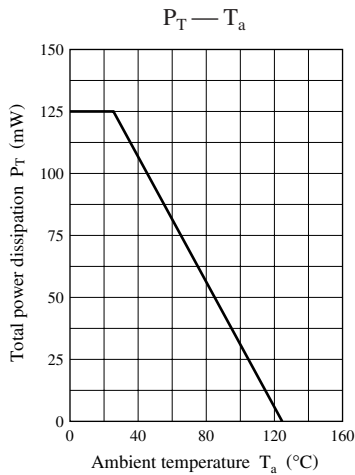
Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)		$V_{CBO}$	$I_C = -10 \mu\text{A}, I_E = 0$	-50			V
Collector-emitter voltage (Base open)		$V_{CEO}$	$I_C = -2 \text{mA}, I_B = 0$	-50			V
Collector-base cutoff current (Emitter open)		$I_{CBO}$	$V_{CB} = -50 \text{V}, I_E = 0$			-0.1	$\mu\text{A}$
Collector-base cutoff current (Emitter open)		$I_{CEO}$	$V_{CE} = -50 \text{V}, I_B = 0$			-0.5	$\mu\text{A}$
Emitter-base cutoff current (Collector open)	UNR9115J/9116J/9117J/911BJ	$I_{EBO}$	$V_{EB} = -6 \text{V}, I_C = 0$			-0.01	mA
	UNR9110J/9113J/911AJ					-0.1	
	UNR9112J/9114J/911DJ/ 911EJ/911MJ/911NJ/911TJ					-0.2	
	UNR9111J					-0.5	
	UNR911FJ/911HJ					-1.0	
	UNR9119J					-1.5	
	UNR9118J/911CJ/911LJ/911VJ					-2.0	
Forward current transfer ratio	UNR911VJ	$h_{FE}$	$V_{CE} = -10 \text{V}, I_C = -5 \text{mA}$	6		20	—
	UNR9118J/911LJ			20			
	UNR9119J/911DJ/911FJ/911HJ			30			
	UNR9111J			35			
	UNR9112J/911EJ			60			
	UNR9113J/9114J/911AJ/ 911CJ/911MJ			80			
	UNR911NJ/911TJ			80	400		
	UNR9110J/9115J/9116J/ 9117J/911BJ			160	460		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -10 \text{mA}, I_B = -0.3 \text{mA}$			-0.25	V	
UNR911VJ					$I_C = -10 \text{mA}, I_B = -1.5 \text{mA}$		
Output voltage high-level		$V_{OH}$	$V_{CC} = -5 \text{V}, V_B = -0.5 \text{V}, R_L = 1 \text{k}\Omega$	-4.9			V
Output voltage low-level		$V_{OL}$	$V_{CC} = -5 \text{V}, V_B = -2.5 \text{V}, R_L = 1 \text{k}\Omega$			-0.2	V
UNR9113J/911BJ			$V_{CC} = -5 \text{V}, V_B = -3.5 \text{V}, R_L = 1 \text{k}\Omega$				
UNR911DJ			$V_{CC} = -5 \text{V}, V_B = -10 \text{V}, R_L = 1 \text{k}\Omega$				
UNR911EJ			$V_{CC} = -5 \text{V}, V_B = -6 \text{V}, R_L = 1 \text{k}\Omega$				
UNR911AJ			$V_{CC} = -5 \text{V}, V_B = -5 \text{V}, R_L = 1 \text{k}\Omega$				
Transition frequency		$f_T$	$V_{CB} = -10 \text{V}, I_E = 1 \text{mA}, f = 200 \text{MHz}$		80		MHz
UNR9113J					150		
UNR911AJ					80		
UNR911CJ					150		
Input resistance	UNR9118J	$R_1$		-30%	0.51	+30%	k $\Omega$
	UNR9119J				1.0		
	UNR911HJ/911MJ/911VJ				2.2		
	UNR9116J/911FJ/911LJ/911NJ				4.7		
	UNR9111J/9114J/9115J				10		
	UNR9112J/9117J/911TJ				22		
	UNR9110J/9113J/911DJ/911EJ				47		
	UNR911AJ/911BJ				100		

■ Electrical Characteristics (continued)  $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

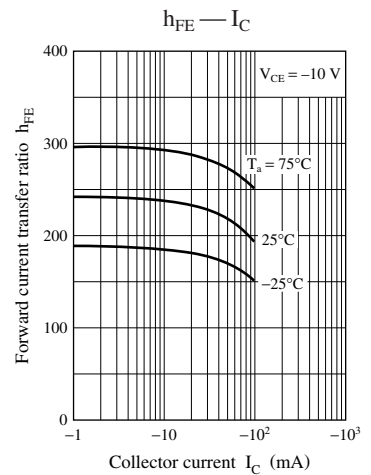
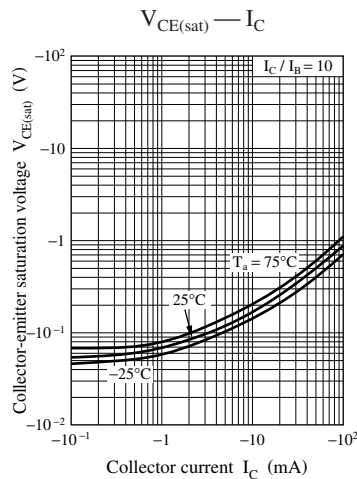
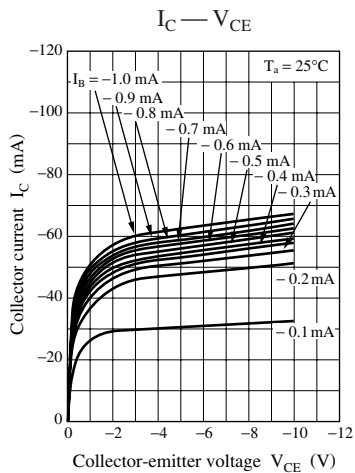
Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Emitter-base resistance	UNR911CJ	$R_2$		-30%	47	+30%	k $\Omega$
Resistance ratio	UNR911MJ	$R_1/R_2$			0.047		—
	UNR911NJ				0.1		
	UNR9118J/9119J			0.08	0.10	0.12	
	UNR9114J			0.17	0.21	0.25	
	UNR911HJ			0.17	0.22	0.27	
	UNR911TJ				0.47		
	UNR911FJ			0.37	0.47	0.57	
	UNR911AJ/911VJ				1.0		
	UNR9111J/9112J/9113J/911LJ			0.8	1.0	1.2	
	UNR911EJ			1.70	2.14	2.60	
UNR911DJ	3.7	4.7	5.7				

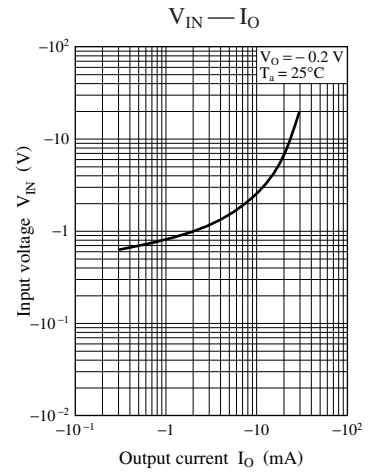
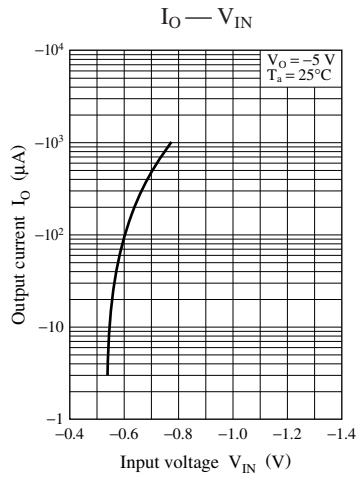
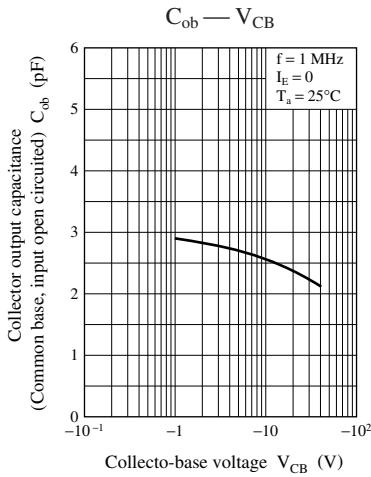
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Common characteristics chart

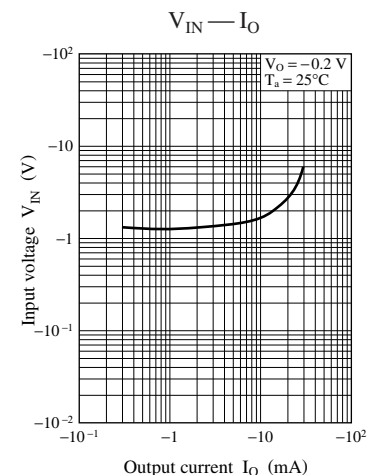
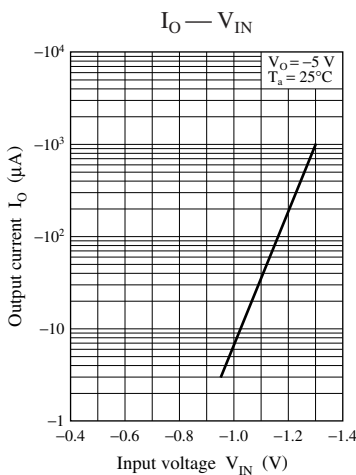
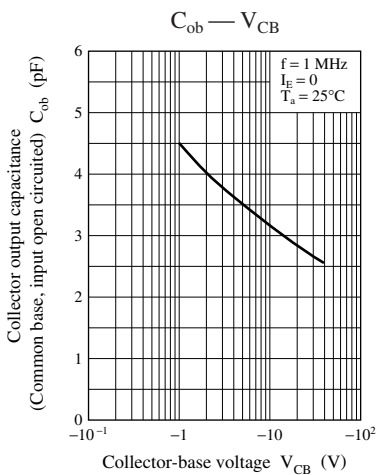
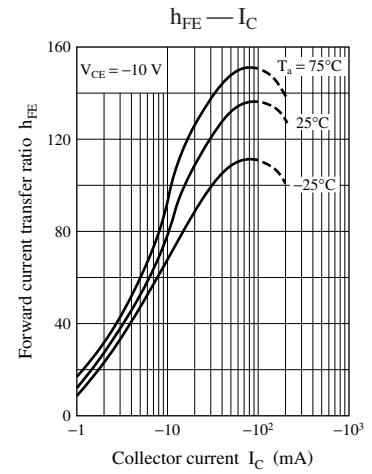
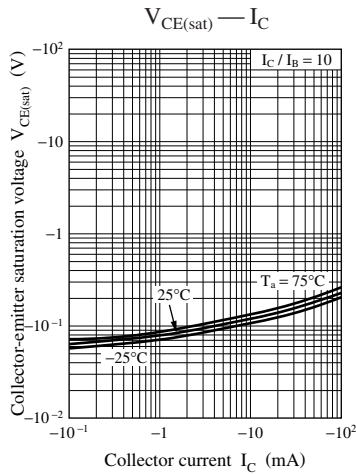
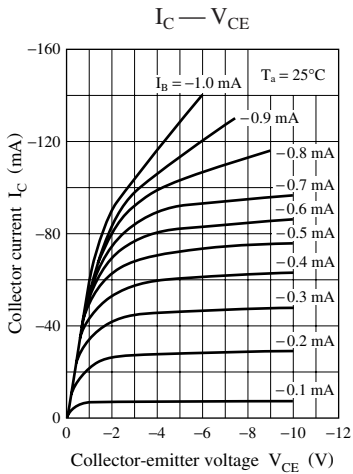


Characteristics charts of UNR9110J

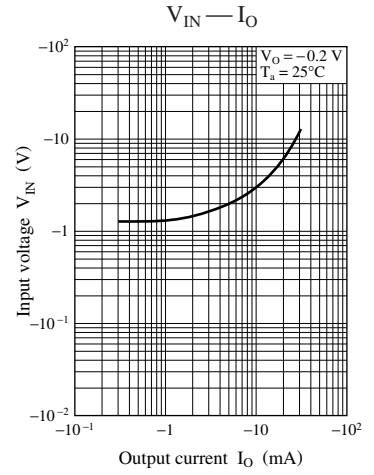
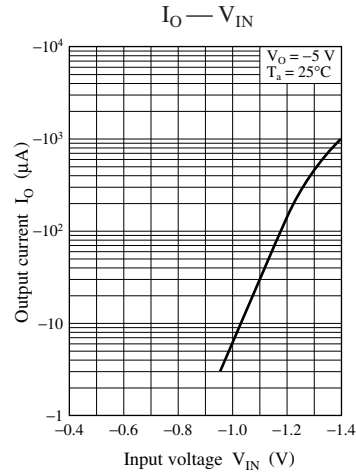
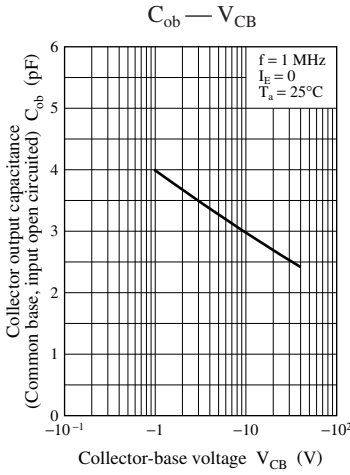
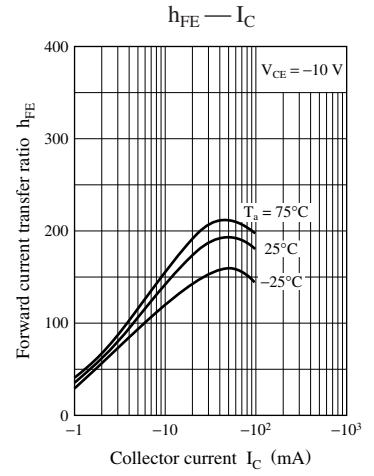
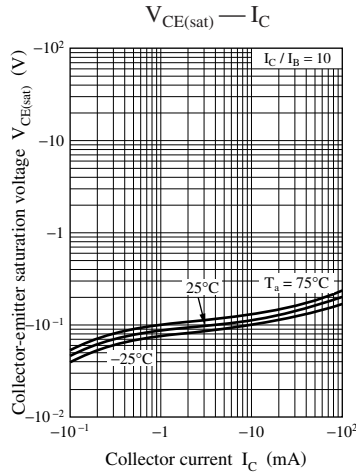
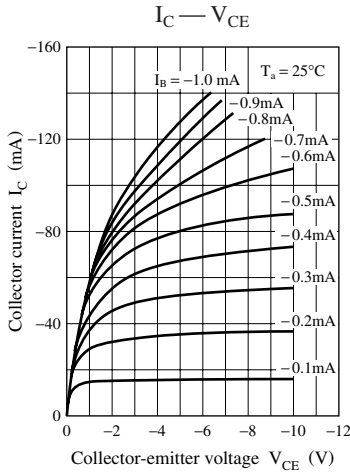




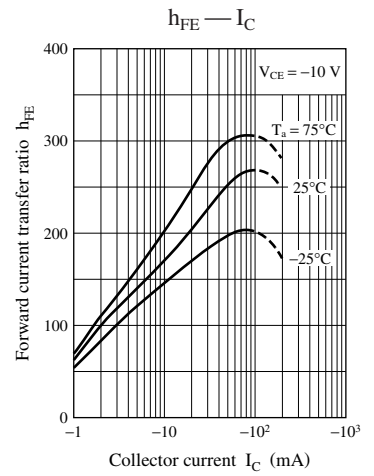
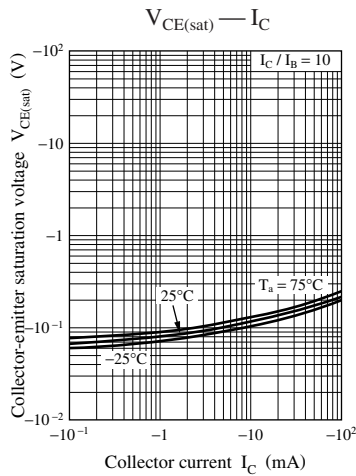
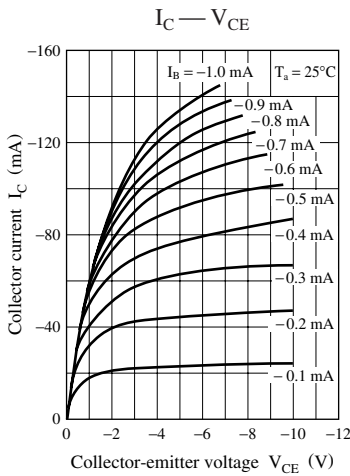
Characteristics charts of UNR9111J

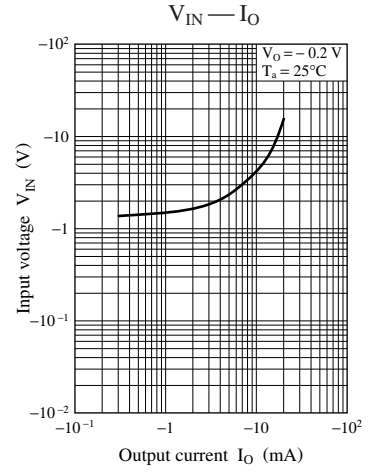
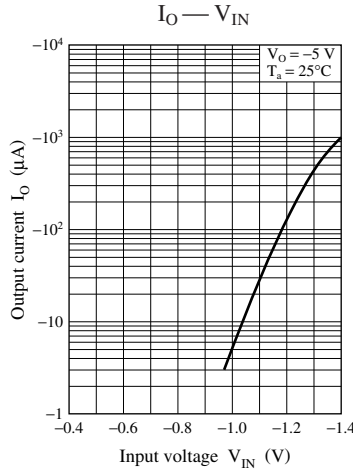
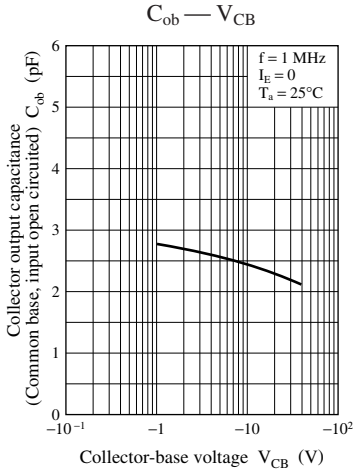


Characteristics charts of UNR9112J

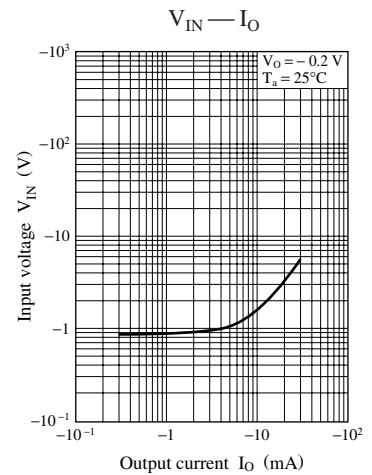
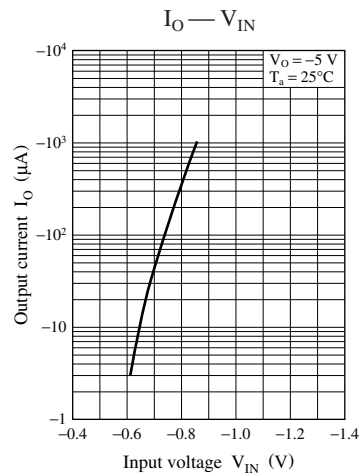
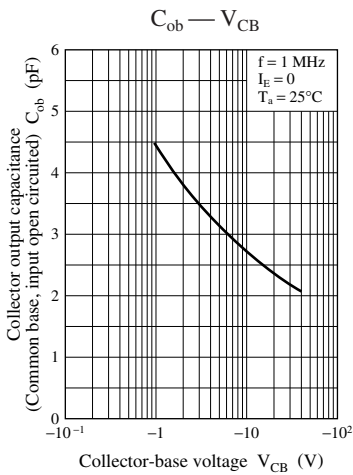
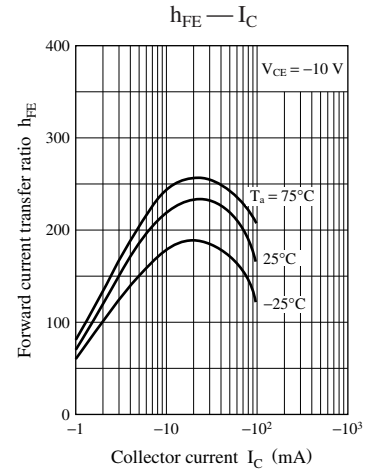
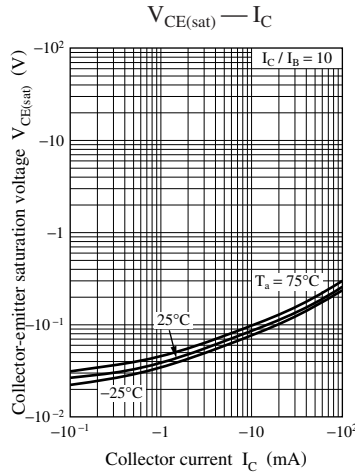
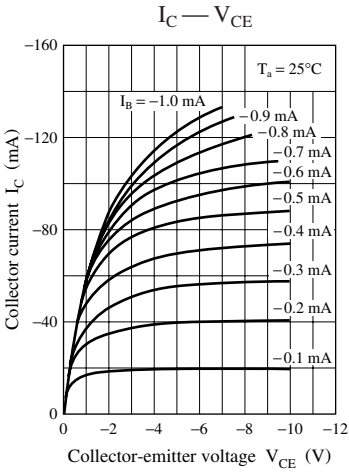


Characteristics charts of UNR9113J

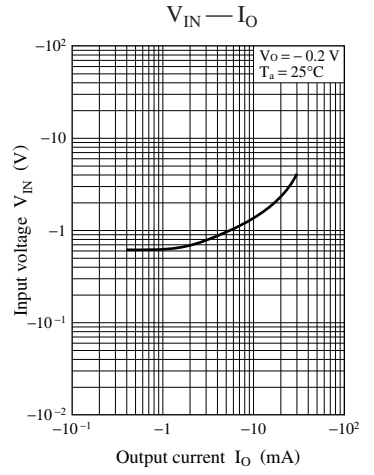
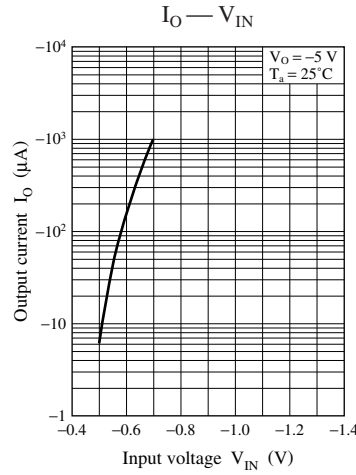
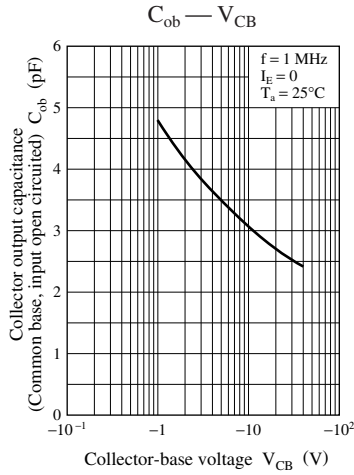
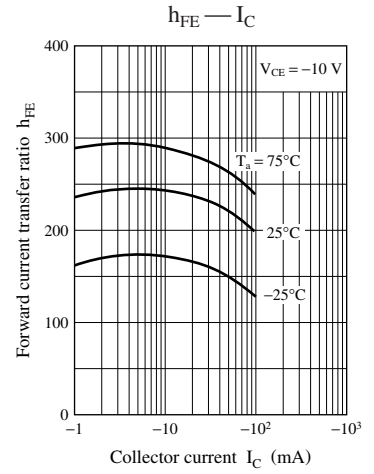
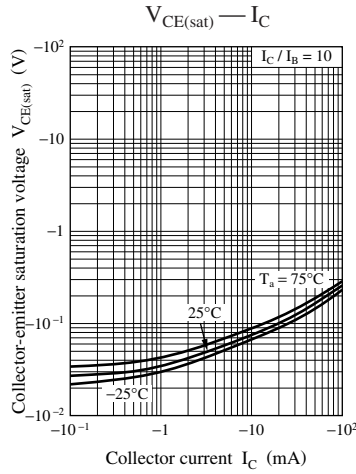
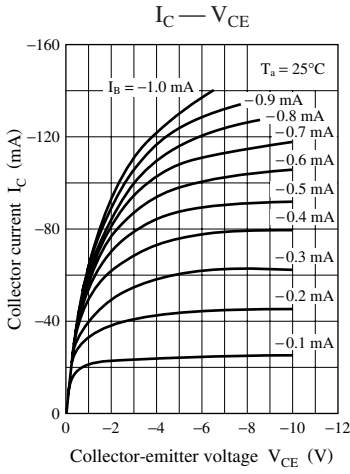




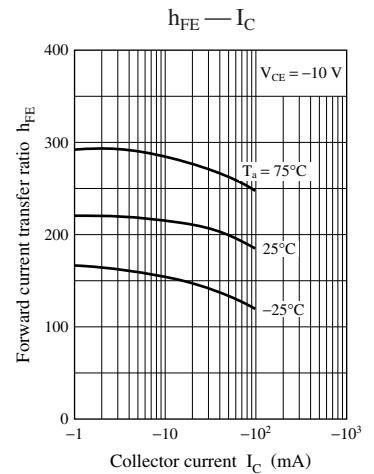
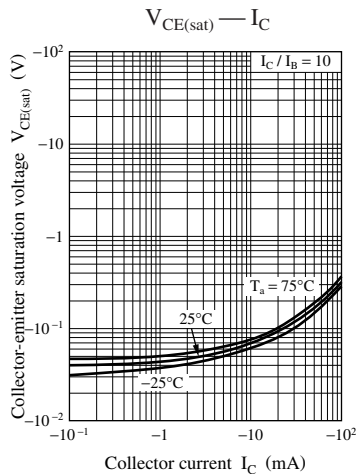
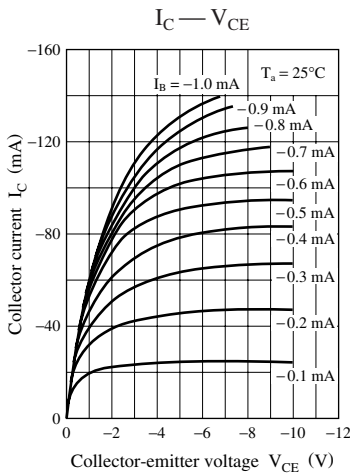
Characteristics charts of UNR9114J

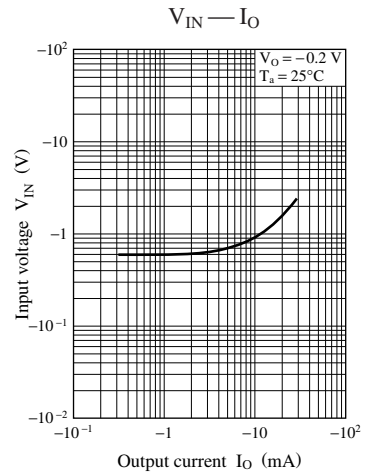
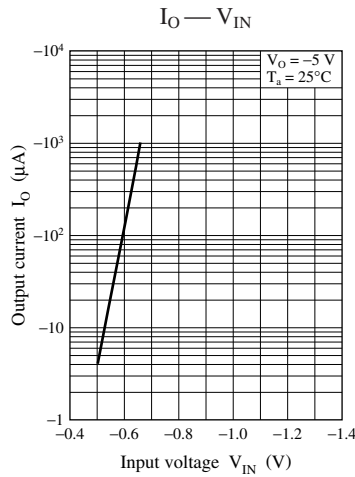
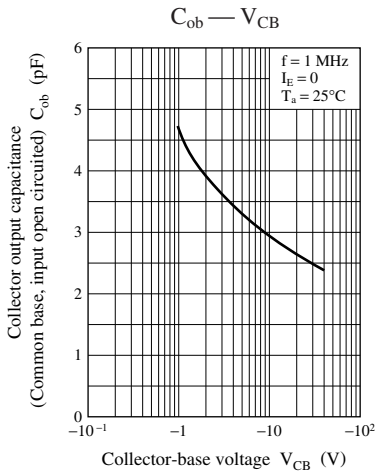


Characteristics charts of UNR9115J

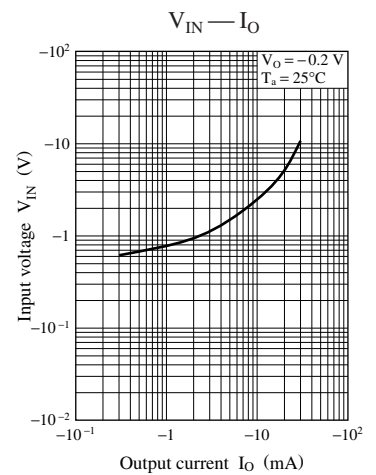
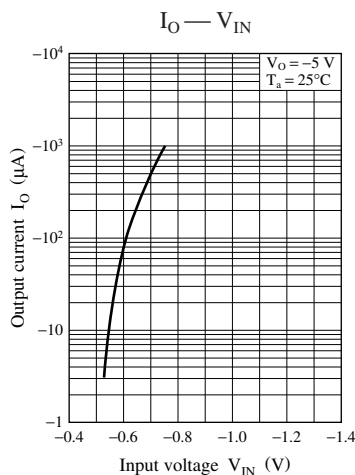
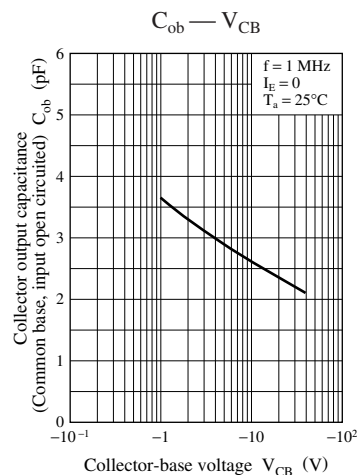
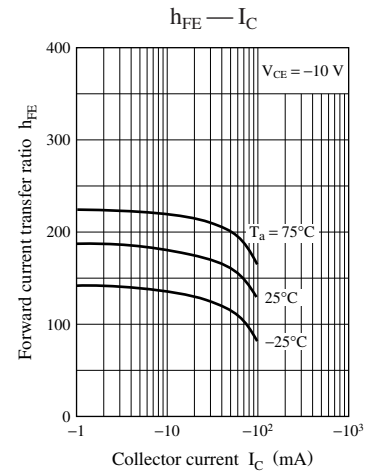
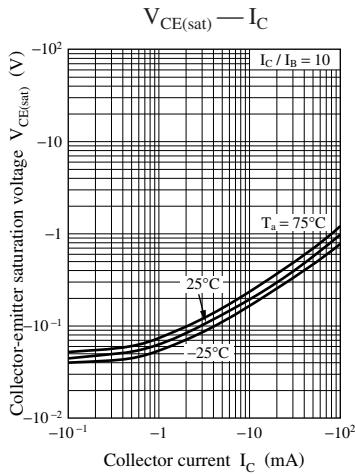
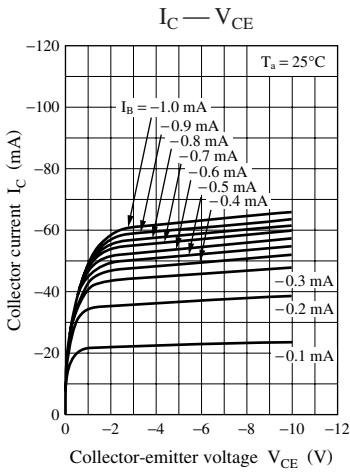


Characteristics charts of UNR9116J



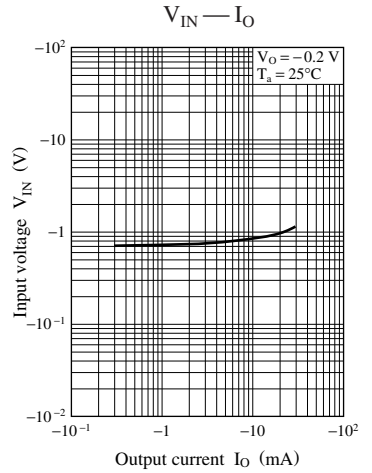
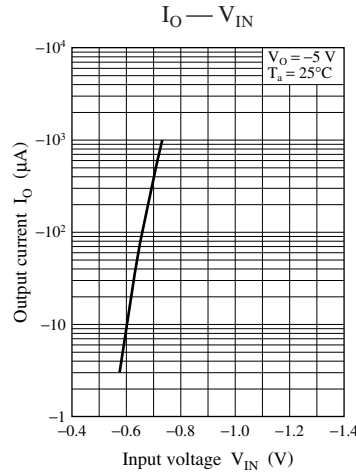
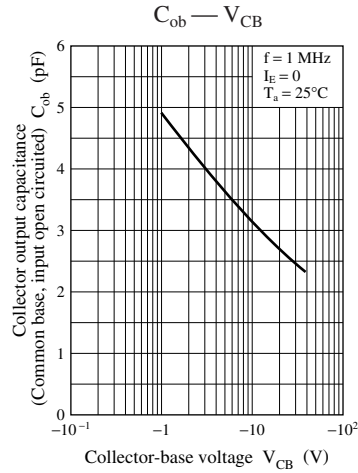
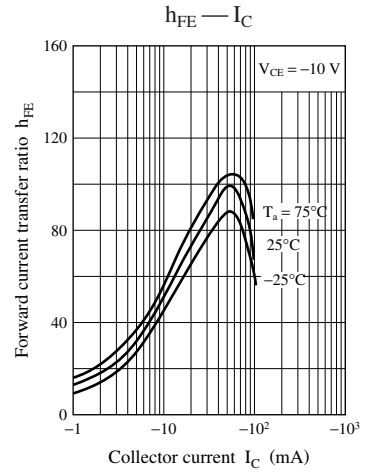
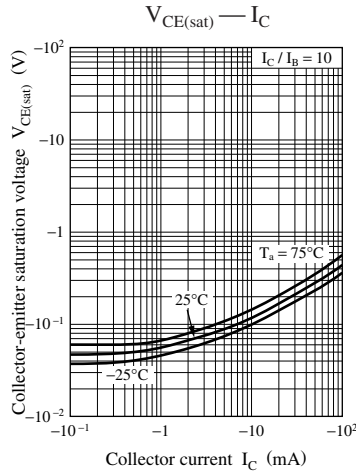
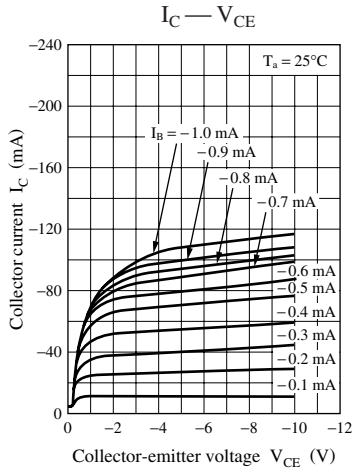


Characteristics charts of UNR9117J

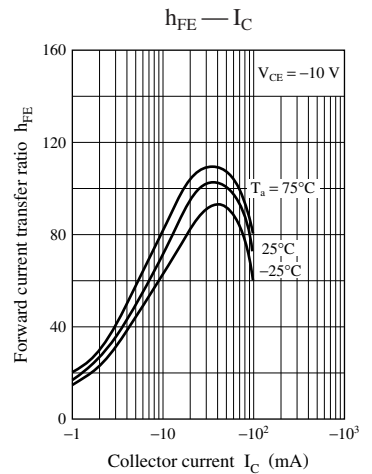
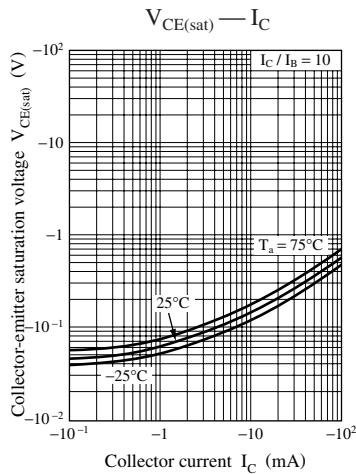
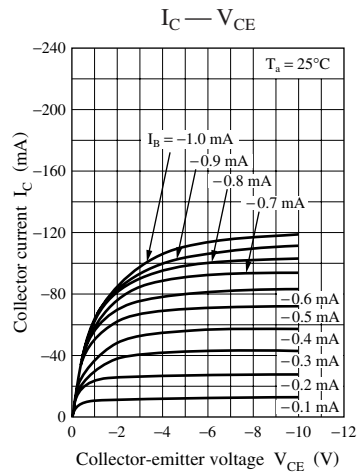


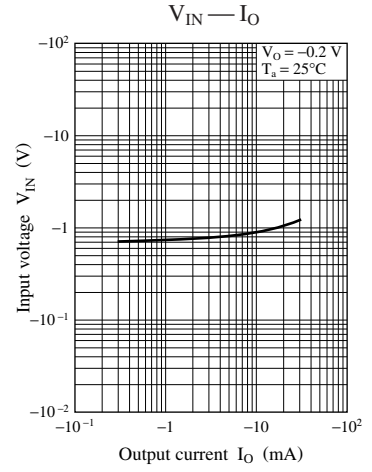
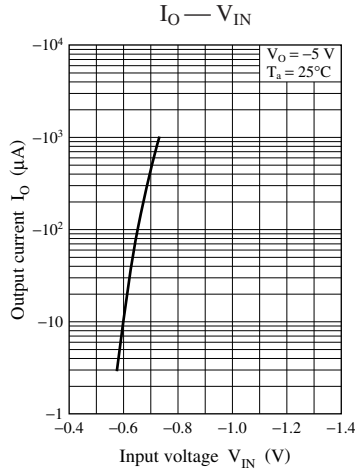
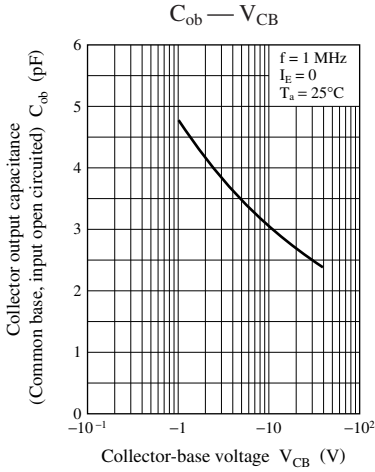


Characteristics charts of UNR9118J

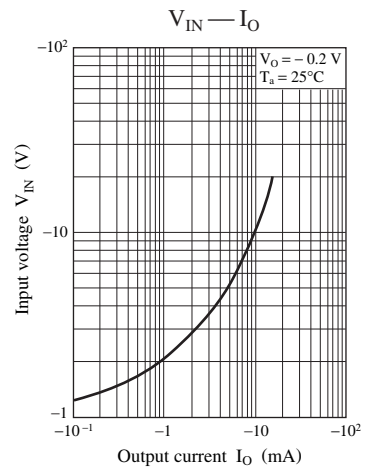
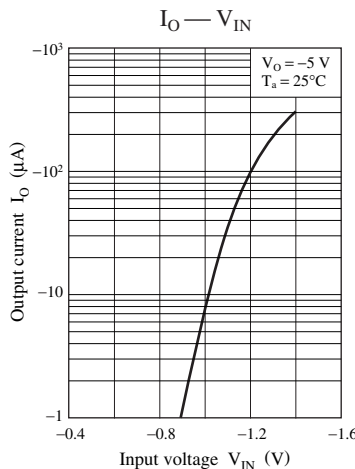
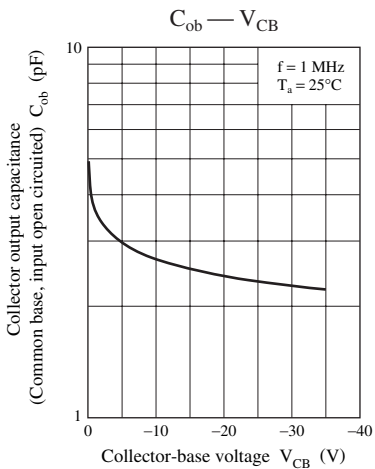
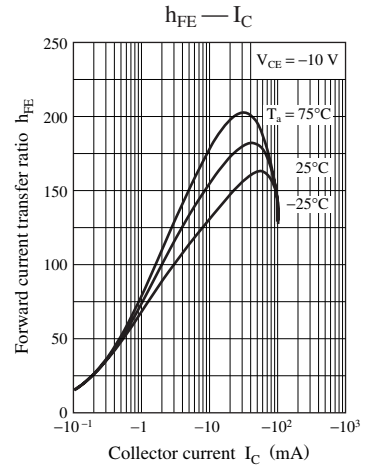
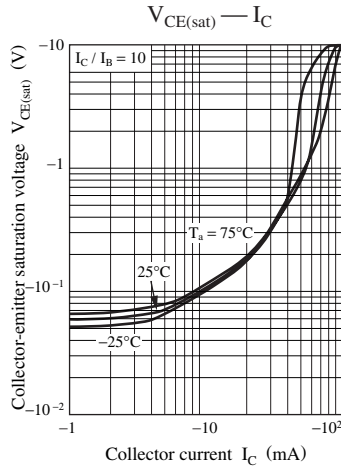
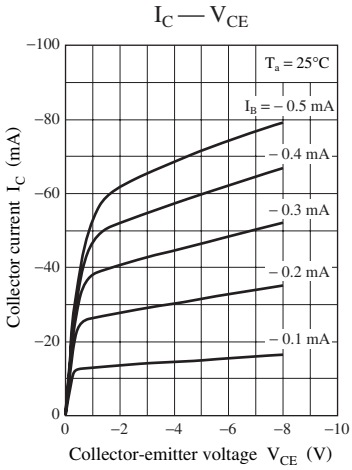


Characteristics charts of UNR9119J

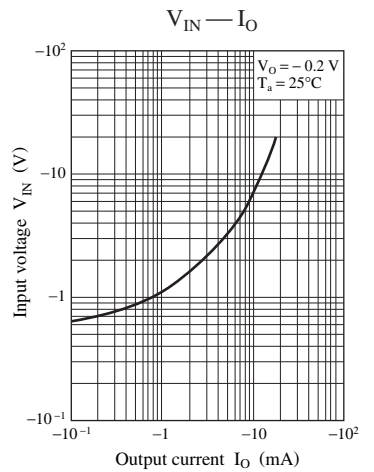
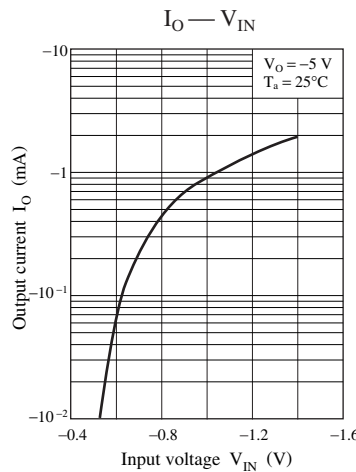
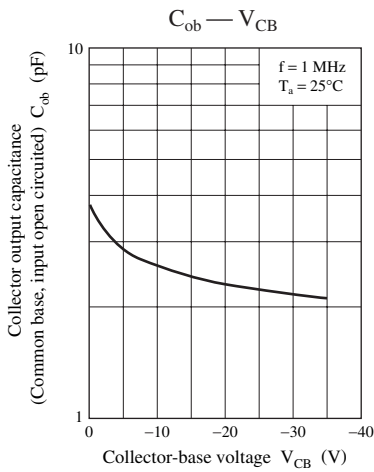
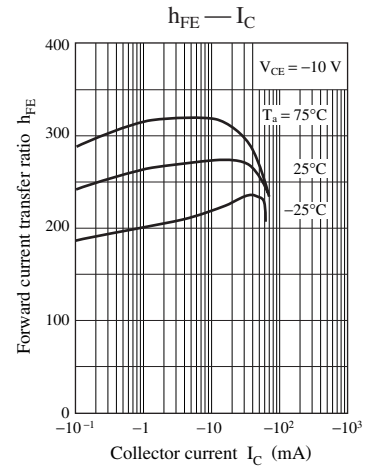
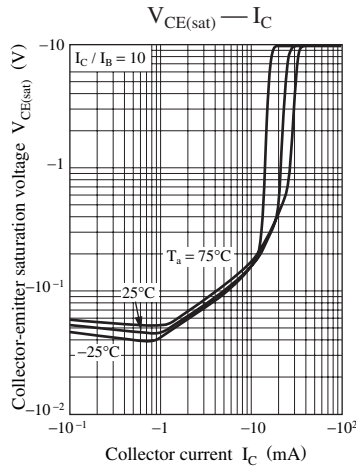
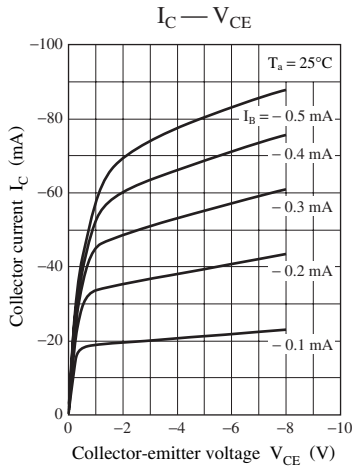




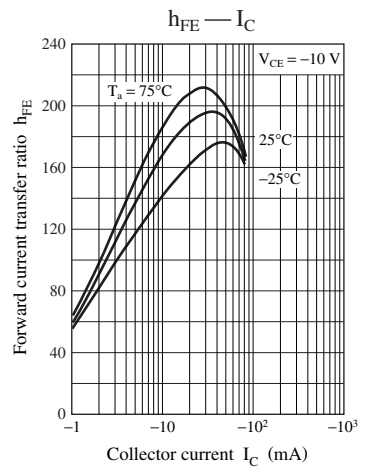
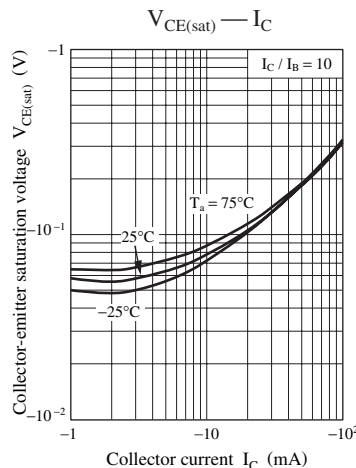
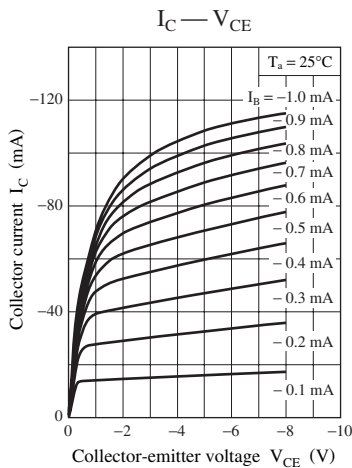
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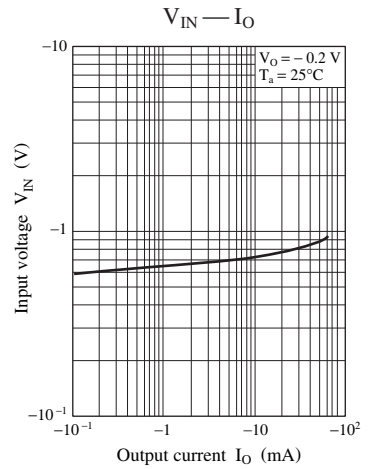
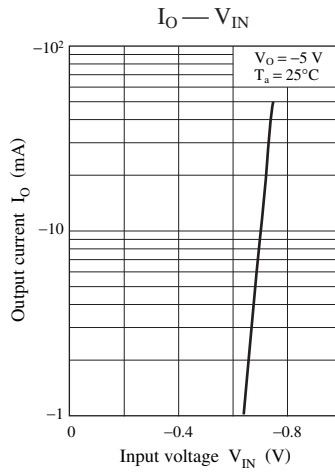
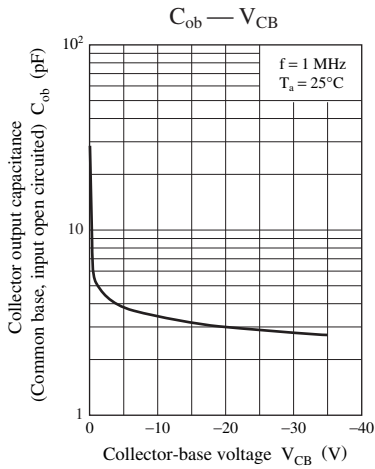


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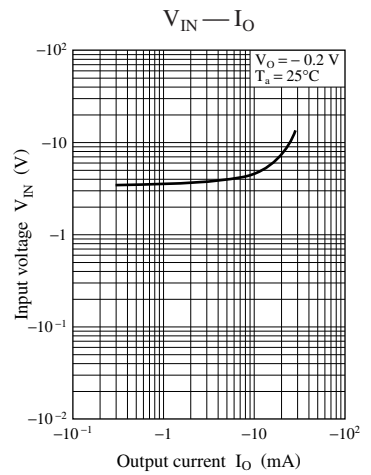
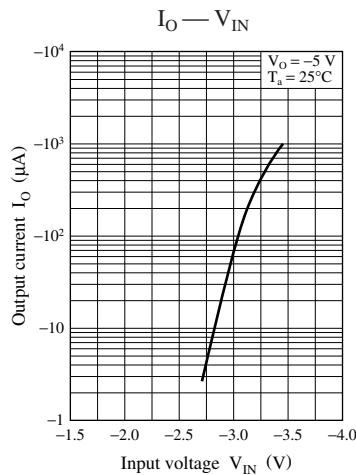
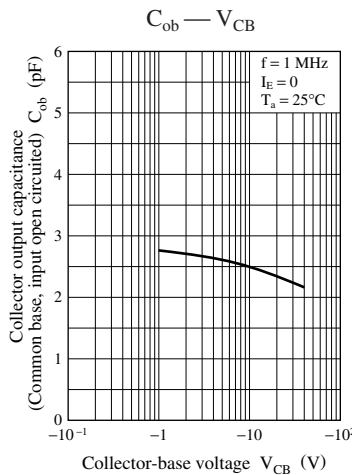
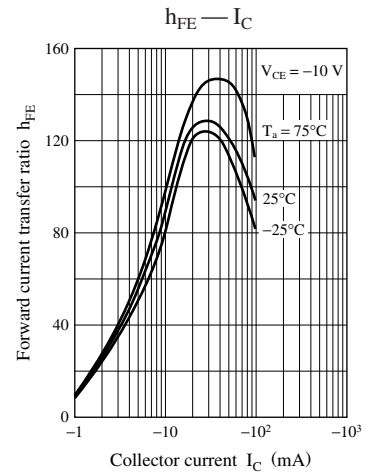
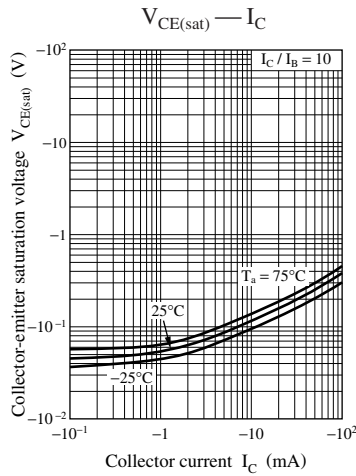
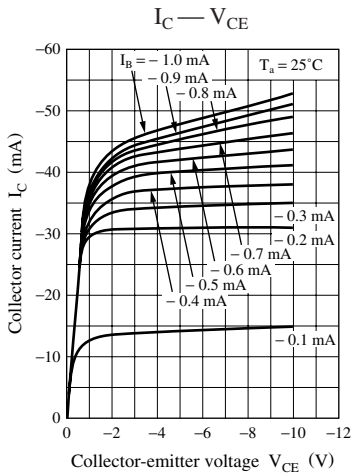


Characteristics charts of UNR911CJ

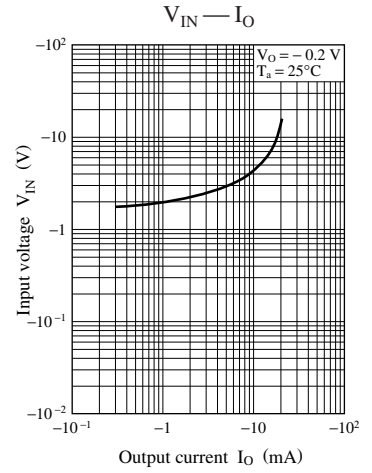
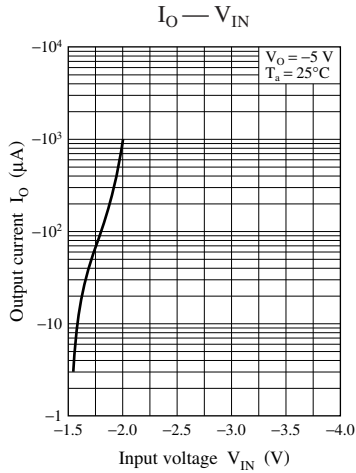
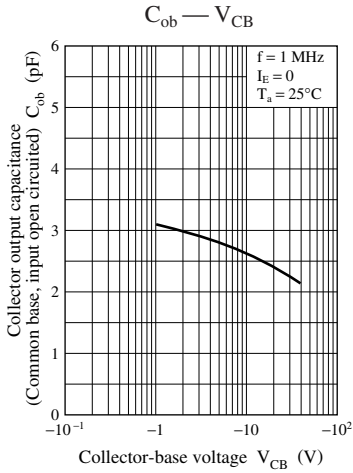
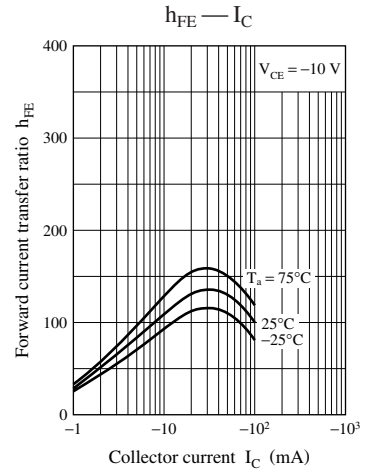
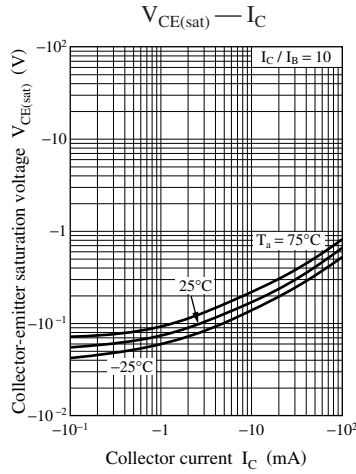
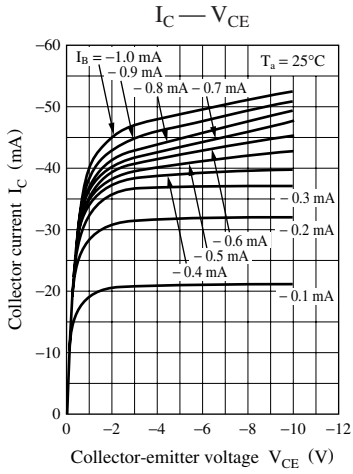




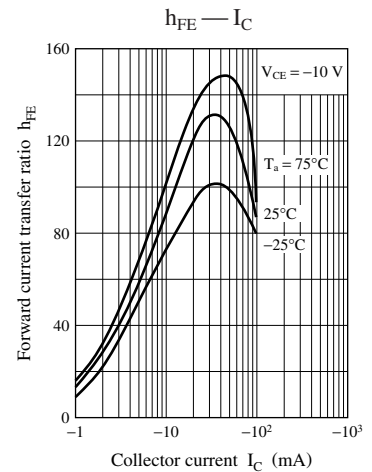
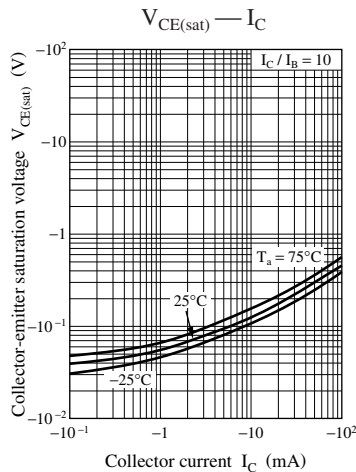
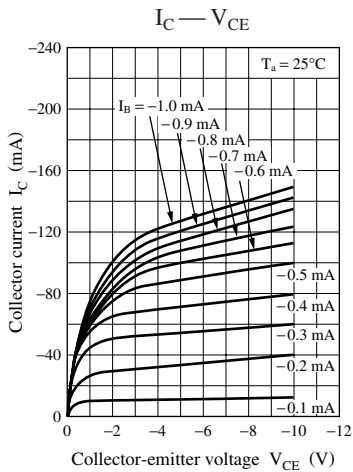
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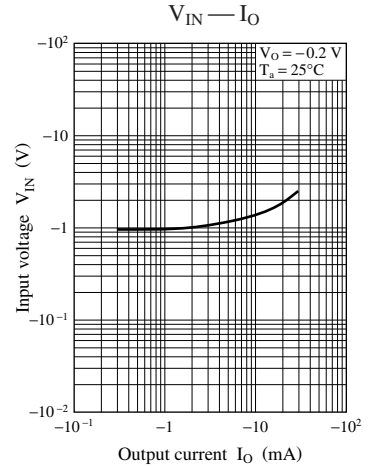
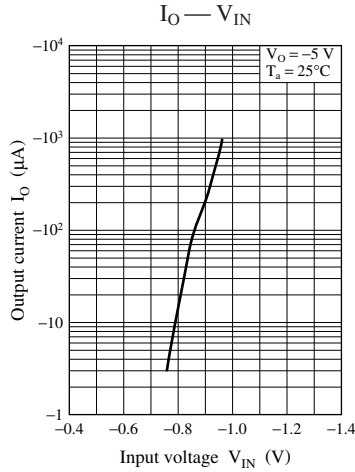
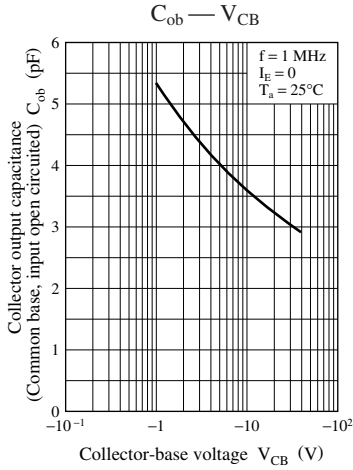


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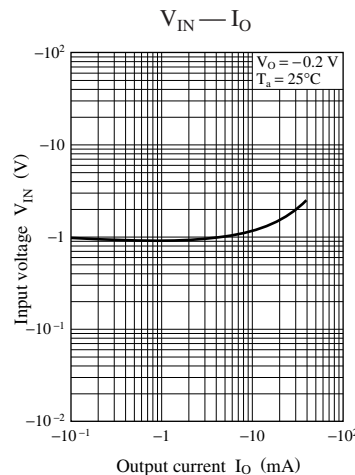
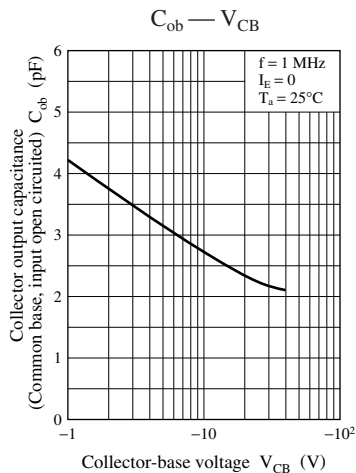
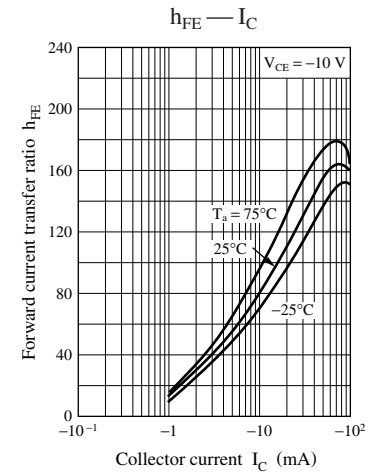
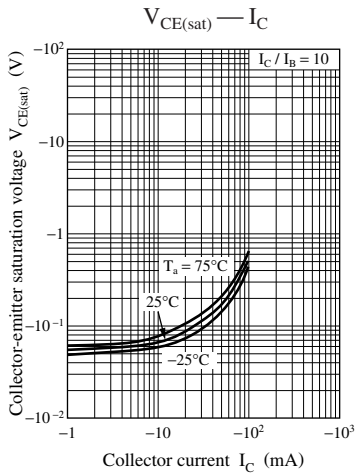
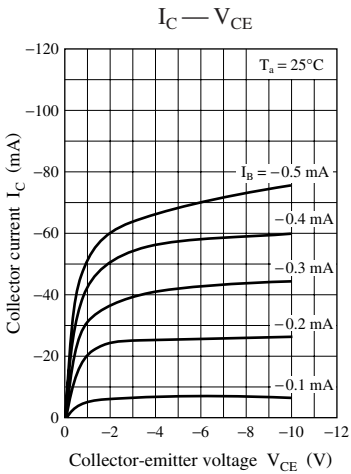


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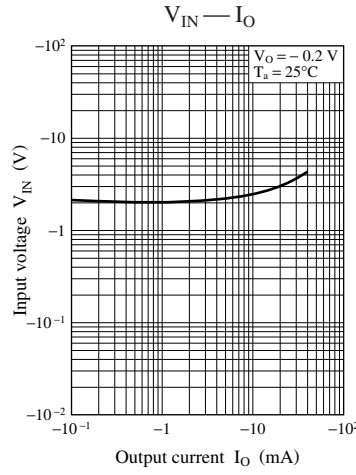
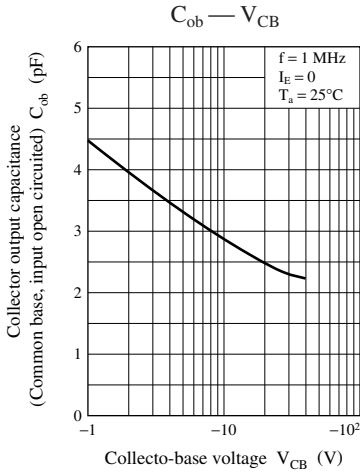
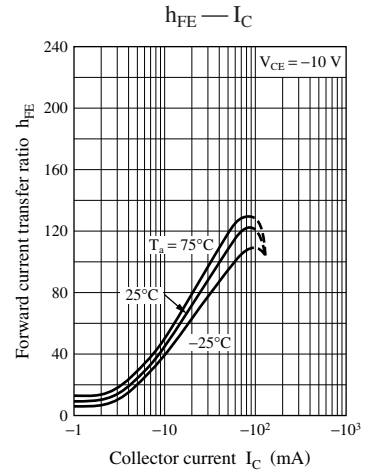
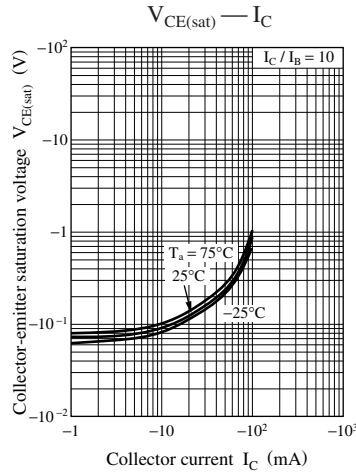
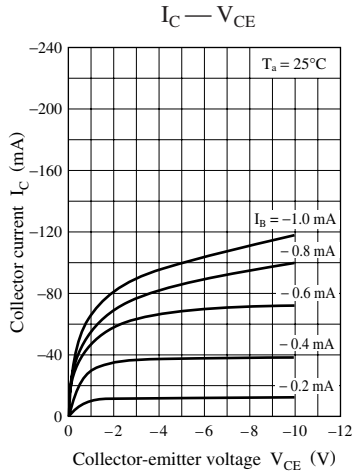




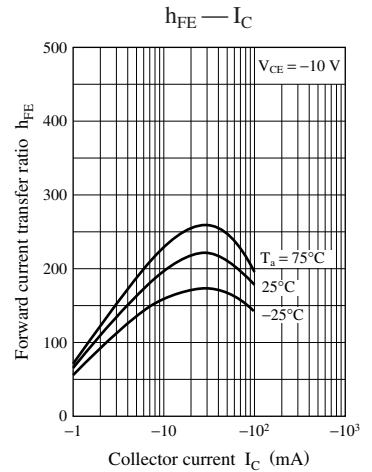
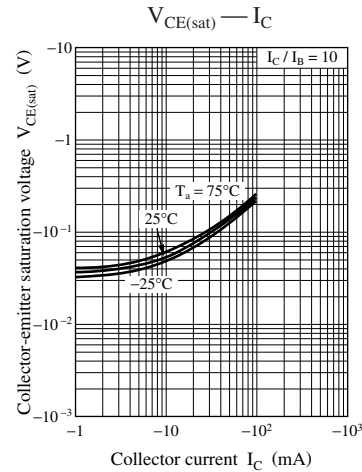
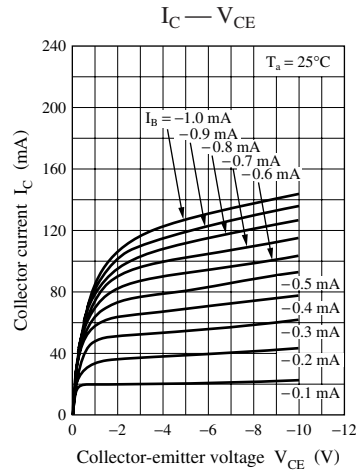
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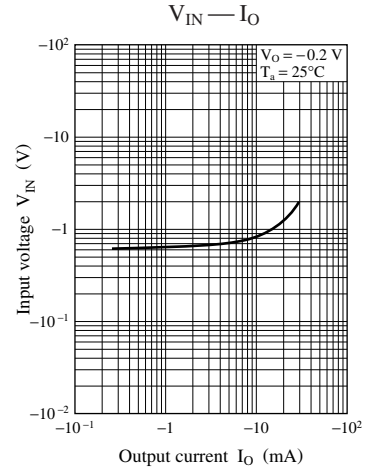
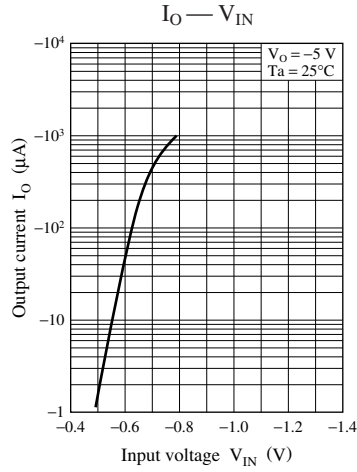
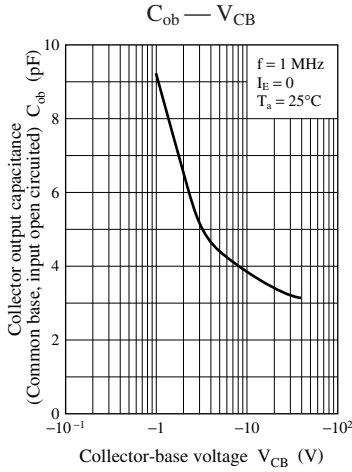


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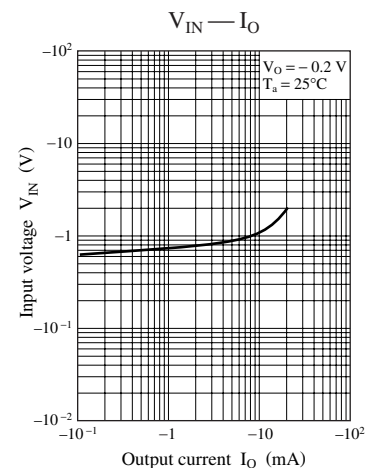
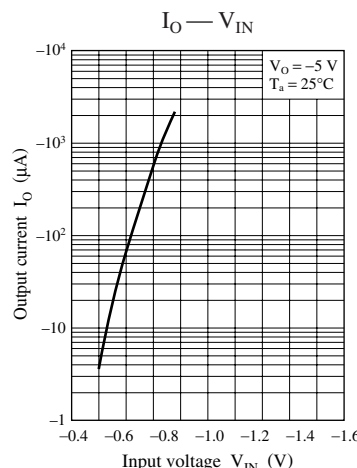
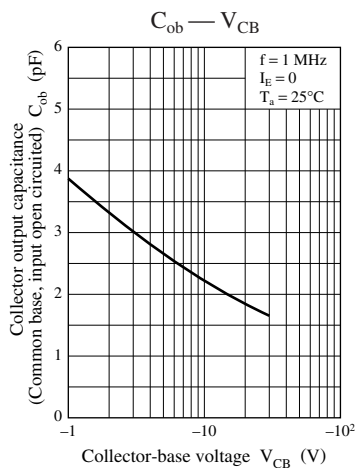
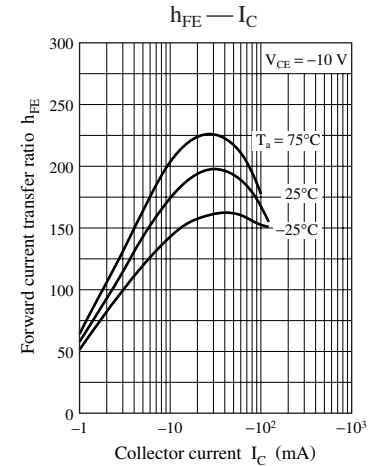
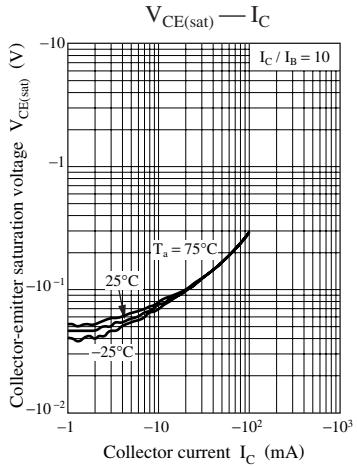
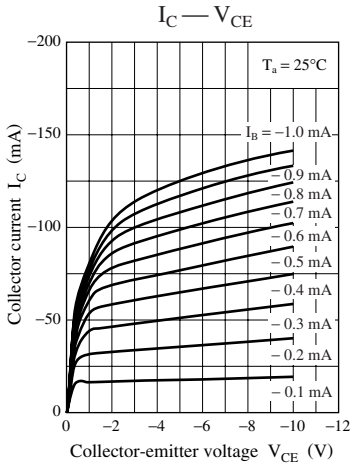


Characteristics charts of UNR911MJ



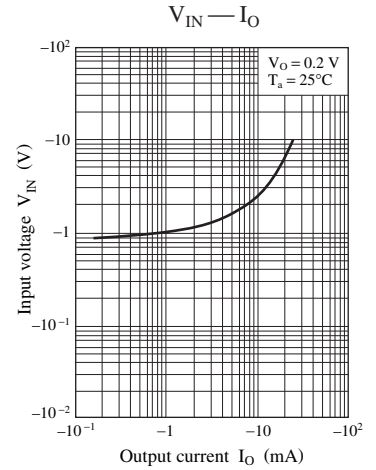
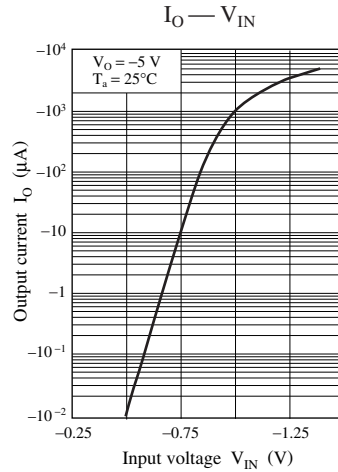
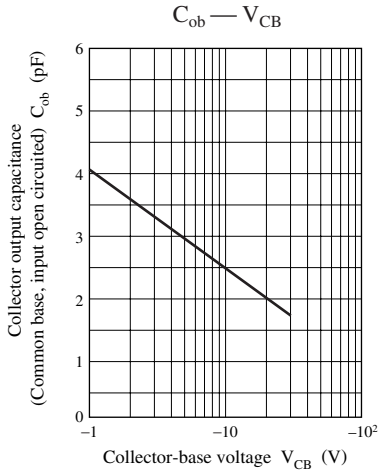
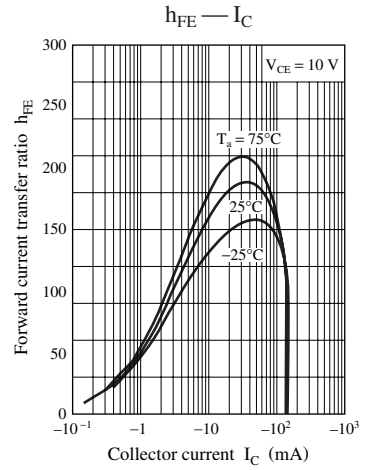
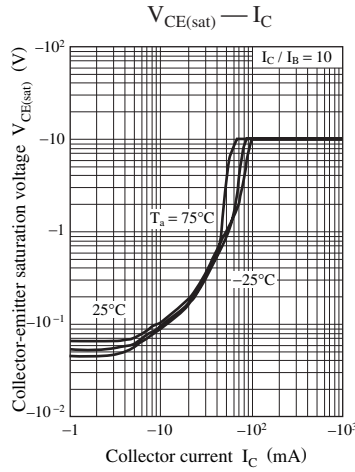
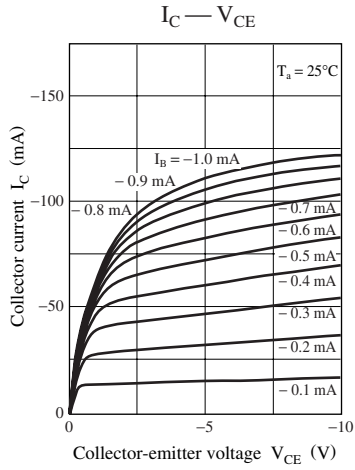


Characteristics charts of UNR911NJ

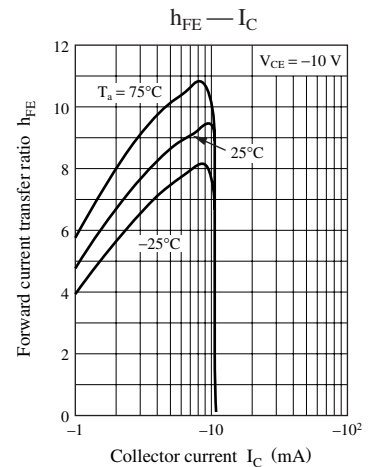
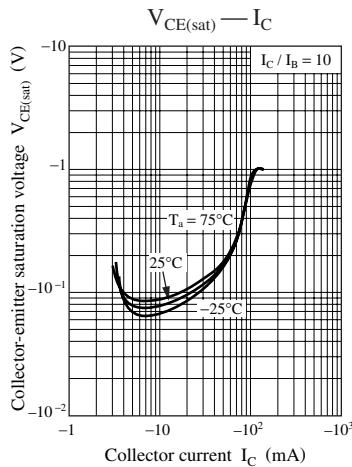
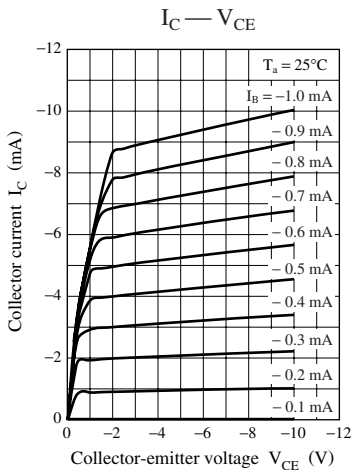


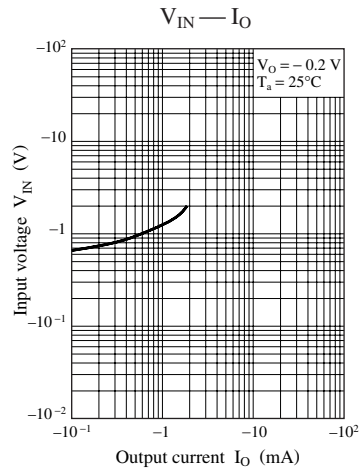
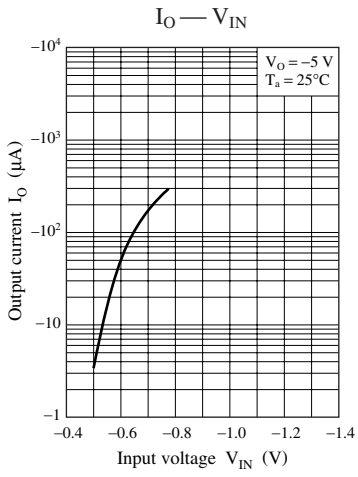


Characteristics charts of UNR911TJ



Characteristics charts of UNR911VJ





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